



**Discrete POWER & Signal
Technologies**

1N4001 - 1N4007

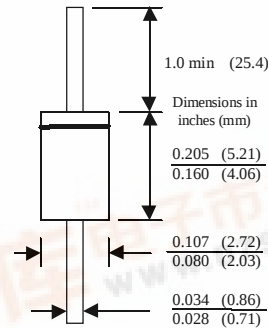
Features

- Low forward voltage drop.
- High surge current capability.



DO-41

COLOR BAND DENOTES CATHODE



1.0 Ampere General Purpose Rectifiers

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
I_O	Average Rectified Current .375 " lead length @ $T_A = 75^\circ\text{C}$	1.0	A
$i_{f(\text{surge})}$	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	30	A
P_D	Total Device Dissipation Derate above 25°C	2.5 20	W mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	50	°C/W
T_{stg}	Storage Temperature Range	-55 to +175	°C
T_J	Operating Junction Temperature	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Parameter	Device							Units
	4001	4002	4003	4004	4005	4006	4007	
Peak Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
DC Reverse Voltage (Rated V_R)	50	100	200	400	600	800	1000	V
Maximum Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	5.0 500							μA μA
Maximum Forward Voltage @ 1.0 A	1.1							V
Maximum Full Load Reverse Current, Full Cycle $T_A = 75^\circ\text{C}$	30							μA
Typical Junction Capacitance $V_R = 4.0\text{ V}$, $f = 1.0\text{ MHz}$	15							pF

General Purpose Rectifiers
(continued)

Typical Characteristics

